

RF-BM-S02, RF-BM-S02A and RF-BM-S02I CC254X Series Bluetooth Low Energy Module

Version 1.0

Shenzhen RF-star Technology Co., Ltd.

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1 Device Overview

1.1 Module Series

There is a series of RF-BM-S02x Bluetooth Low Energy modules. All of them are based on TI CC254X (CC2540 and CC2541) SoC series. Because the CC254X series ICs are compatible in package, pins, and peripherals, those modules are pin-to-pin compatible with each other as well.

Table 1. Module Series of RF-BM-S02x

Model	Antenna Output Mode	Chip Model	TX Power	FLASH	RAM	Peripherals
S02 S02I	PCB onboard IPEX connector	CC2540	+4 dBm	256 KB	8 KB	USB, PWM, ADC, IR, WATCHDOG
S02A	PCB onboard	CC2541	0 dBm	256 KB	8 KB	I2C, PWM, ADC, IR, WATCHDOG

1.2 Description

RF-BM-S02, RF-BM-S02A, and RF-BM-S02I are Bluetooth Low Energy (BLE) module based on TI CC254X (CC2540 and CC2541), an 8051 core BLE System-on-Chip (SoC). This PCB module integrates a 32 MHz crystal, a 32.768 kHz crystal, an LC balun, an RF matching filter, and a meander line PCB antenna (S02 and S02A) or an IPEX connector (S02I). It is pre-programmed with the BLE 4.0 stack and an application communication protocol Very low-power sleep modes are available. Short transition times between operating modes further enable low power consumption. RF-BM-S02 is pin-compatible with the RF-BM-S02A and RF-BM-S02I in SMT package, if the USB is not used on the RF-BM-S02 & RF-BM-S02I and the I²C/extra I/O is not used on the RF-BM-S02A. Compared to the RF-BM-S02 and RF-BM-S02I, the RF-BM-S02A provides lower RF current consumption. The RF-BM-S02A does not have the USB interface of the RF-BM-S02 and RF-BM-S02I, and provides lower maximum output power in TX mode. The RF-BM-S02A also adds a HW I²C interface.

1.3 Key Features

- RF
 - Bluetooth low energy compatible protocol stack for single-mode
 - Excellent link budget (up to 97 dBm),
 Enabling long-range applications without external front end
 - Accurate Digital Received Signal-Strength

Indicator (RSSI)

- Microcontroller
- High-performance and low-power 8051 microcontroller core
- In-system-programmable flash of 256 KB
- 8-KB SRAM
- Peripherals



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- 12 Bit ADC with eight channels and configurable resolution
- Integrated high-power op-amp and ultra-low power comparator
- General-purpose timers (one 16-bits, two 8-bits)
- 13 General-purpose I/O pins
- 32 kHz sleep timer with capture
- Two powerful USARTs with support for several serial protocols
- IR generation Circuity
- AES security coprocessor
- Battery monitor and temperature sensor
- RF-BM-S02/S02I:
 - > Full speed USB interface
 - > Each CC2540 contains a unique 48-bit

IEEE address

- RF-BM-S02A:
- ▶ I²C interface
- 2 I/O pins have LED driving capabilities
- Low Power
 - Active mode RX down to 19.6 mA
 - Active mode TX (-6 dBm): 24 mA
 - Power mode 1 (3-μs wake-up): 235 μA
 - Power mode 2 (sleep timer on): 0.9 µA
 - Power mode 3 (external interrupts): 0.4 µA
 - Wide supply voltage range (2 V ~ 3.6 V)
 - Full RAM and register retention in all power modes
- Dimension: 15.2 mm x 11.2 mm SMT Package

1.4 Applications

- 2.4-GHz Bluetooth low energy system
- Mobile phone accessories
- Sports and leisure equipment
- Consumer electronics
- Human interface devices

- Keyboard, mouse
- Remote control
- USB dongles
- Health care and medical
- Smart lighting

1.5 Functional Block Diagram

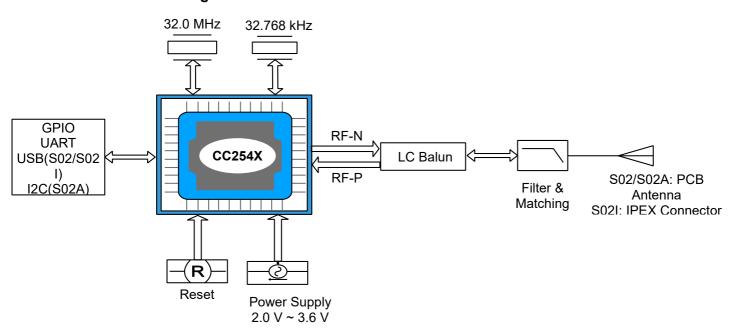


Figure 1. Functional Block Diagram of RF-BM-S02x



1.6 Part Number Conventions

The part numbers are of the form of RF-BM-S02x where the fields are defined as follows:

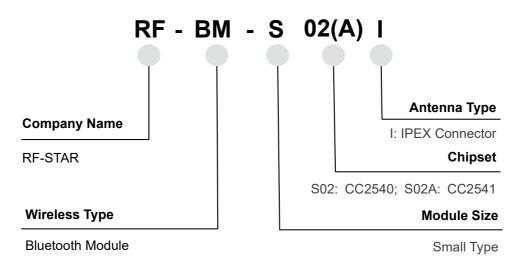


Figure 2. Part Number Conventions of RF-BM-S02x



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2 Module Configuration and Functions

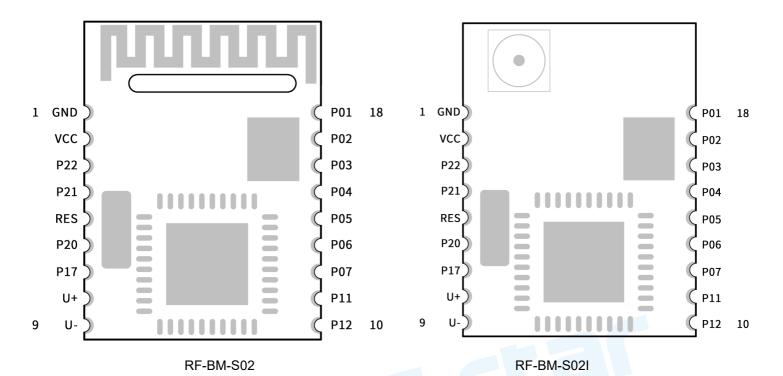
2.1 Module Parameters

Table 2. Parameters of RF-BM-S02x

Chipset RF-BM-S02/S02I: CC2540 RF-BM-S02A: CC2541 Supply Power Voltage 2.0 V ~ 3.6 V, recommended to 3.3 V Frequency 2402 MHz ~ 2480 MHz RF-BM-S02/S02I: -23.0 dBm ~ +4.0 dBm RF-BM-S02A: -23.0 dBm ~ +4.0 dBm Receiving Sensitivity (low-gain mode) -87 dBm Receiving Sensitivity (high-gain mode) -93 dBm GPIO 13 Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	1	Table 2. Parameters of RF-BM-S02x		
Frequency 2402 MHz ~ 2480 MHz	Chipset			
Transmit Power RF-BM-S02/S02I: -23.0 dBm ~ +4.0 dBm Receiving Sensitivity (low-gain mode) -87 dBm Receiving Sensitivity (high-gain mode) -93 dBm GPIO 13 Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 2 (sleep timer on) 0.9 μA	Supply Power Voltage	2.0 V ~ 3.6 V, recommended to 3.3 V		
Transmit Power RF-BM-S02A: -23.0 dBm ~ 0 dBm Receiving Sensitivity (low-gain mode) -87 dBm Receiving Sensitivity (high-gain mode) -93 dBm GPIO 13 Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 2 (sleep timer on) 0.9 μA	Frequency	2402 MHz ~ 2480 MHz		
Receiving Sensitivity (high-gain mode) -93 dBm GPIO 13 Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Transmit Power			
GPIO 13 Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Receiving Sensitivity (low-gain mode)	-87 dBm		
Crystal 32 MHz RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Receiving Sensitivity (high-gain mode)	-93 dBm		
RAM 8 KB Flash 256 KB Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	GPIO	13		
Flash 256 KB SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Crystal	32 MHz		
Package SMT Packaging (1.27-mm half-hole pitch stamp stick) Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	RAM	8 KB		
Frequency Error ±20 kHz Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Flash	256 KB		
Dimension 15.2 mm x 11.2 mm x 1.7 mm Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Package	SMT Packaging (1.27-mm half-hole pitch stamp stick)		
Type of Antenna PCB Antenna Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) Power mode 2 (sleep timer on) 0.9 μA	Frequency Error	±20 kHz		
Operating Temperature -40 °C ~ +85 °C Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Dimension	15.2 mm x 11.2 mm x 1.7 mm		
Storage Temperature -40 °C ~ +125 °C RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-µs wake-up) 235 µA Power mode 2 (sleep timer on) 0.9 µA	Type of Antenna	PCB Antenna		
RX Current 19.6 mA TX Current (-6 dBm) 24.0 mA Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	Operating Temperature	-40 °C ~ +85 °C		
TX Current (-6 dBm) 24.0 mA Power mode 1 (3-µs wake-up) 235 µA Power mode 2 (sleep timer on) 0.9 µA	Storage Temperature	-40 °C ~ +125 °C		
Power mode 1 (3-μs wake-up) 235 μA Power mode 2 (sleep timer on) 0.9 μA	RX Current	19.6 mA		
Power mode 2 (sleep timer on) 0.9 µA	TX Current (-6 dBm)	24.0 mA		
•	Power mode 1 (3-µs wake-up)	235 μΑ		
	Power mode 2 (sleep timer on)	0.9 μΑ		
Power mode 3 (external interrupts) 0.4 µA	Power mode 3 (external interrupts)	0.4 μΑ		



2.2 Module Pin Diagram



GND P01 1 18 VCC P02 P22 P03 P21 P04 **RST** P05 P20 P06 P17 P07 I^2C_SCL P11 9 I²C_SDA P12 10

Figure 3. Pin Diagram of RF-BM-S02x

RF-BM-S02A



2.3 Pin Functions

Table 3. Pin Functions of RF-BM-S02x

Pin	Name	Chip Pin	Pin Type	Description
1	GND		GND	Ground
		-		
2	VCC	-	Power	Power supply 2.0 V ~ 3.6 V
3	P22	P2_2	I/O	
4	P21	P2_1	I/O	
5	RESET	RST	RESET	Reset, active low.
6	P20	P2_0	I/O	
7	P17	P1_7	I/O	
_	USB_P	USB+	USB+	USB+ (For RF-BM-S02 and RF-BM-S02I)
8	I2C_SCL	I2C_SCL	I/O	I2C_SCL (For RF-BM-S02A)
	USB_N	USB-	USB-	USB- (For RF-BM-S02 and RF-BM-S02I)
9	I2C_SDA	I2C_SDA	I/O	I2C_SDA (For RF-BM-S02A)
10	P12	P1_2	I/O	
11	P11	P1_1	I/O	
12	P07	P0_7	I/O	
13	P06	P0_6	I/O	
14	P05	P0_5	I/O	
15	P04	P0_4	I/O	
16	P03	P0_3	I/O	
17	P02	P0_2	I/O	
18	P01	P0_1	I/O	



3 Specifications

3.1 Recommended Operating Conditions

Functional operation does not guarantee performance beyond the limits of the conditional parameter values in the table below. Long-term work beyond this limit will affect the reliability of the module more or less.

Table 4. Recommended Operating Conditions of RF-BM-S02x

Items	Condition	Min.	Тур.	Max.	Unit
Operating Supply Voltage	Battery Mode	2.0	3.3	3.6	V
Operating Temperature	1	-40	+25	+85	°C
Environmental Hot Pendulum	1	-20		+20	°C/min

3.2 Handling Ratings

Table 5. Handling Ratings of RF-BM-S02x

Items	Condition	Min.	Тур.	Max.	Unit
Storage Temperature	Tstg	-40	+25	+125	\mathbb{C}
Human Body Model	НВМ		±2000		V
Moisture Sensitivity Level			3		
Charged Dev <mark>ice M</mark> odel			±750		V



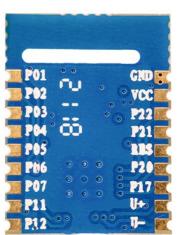
4 Application, Implementation, and Layout

4.1 Module Photos









RF-BM-S02

RF-BM-S02A





RF-BM-S02I

Figure 4. Photos of RF-BM-S02x



4.2 Recommended PCB Footprint

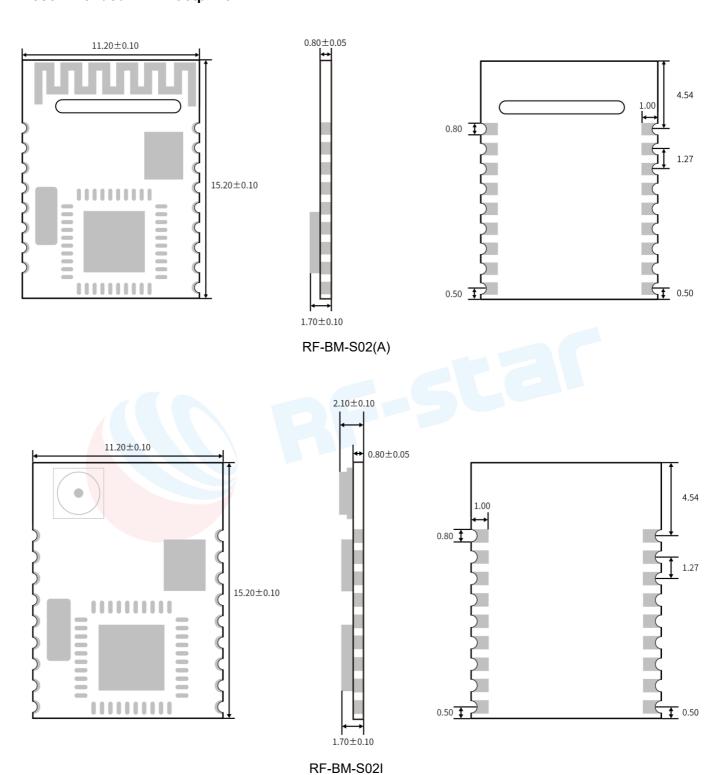


Figure 5. Recommended PCB Footprint of RF-BM-S02 (mm)



4.3 Schematic Diagram

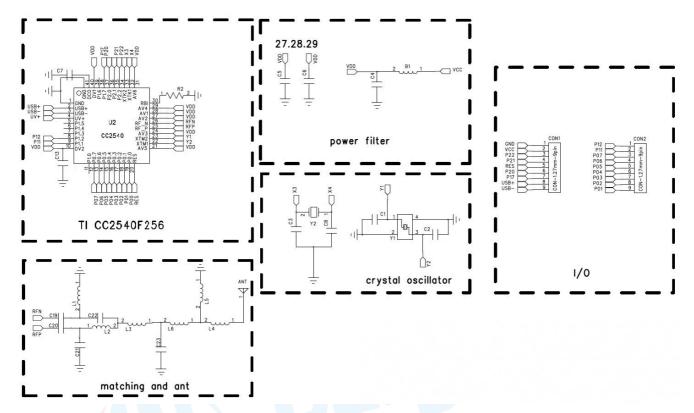


Figure 6. Schematic Diagram of RF-BM-S02x

4.4 Reference Design

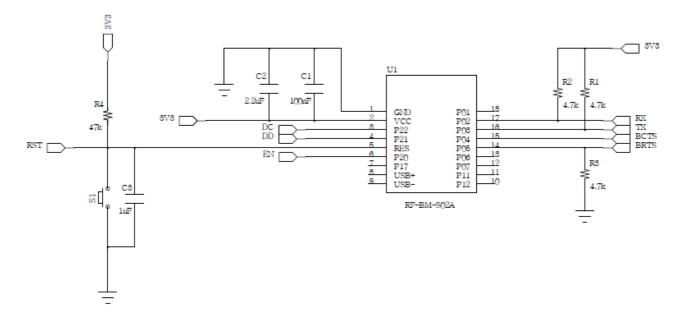


Figure 7. Reference Design of RF-BM-S02x



4.5 Antenna

4.5.1 Antenna Design Recommendation

- 1. The antenna installation structure has a great influence on the module performance. It is necessary to ensure the antenna is exposed and preferably vertically upward. When the module is installed inside of the case, a high-quality antenna extension wire can be used to extend the antenna to the outside of the case.
- The antenna must not be installed inside the metal case, which will cause the transmission distance to be greatly weakened.
- 3. The recommendation of antenna layout.

The inverted-F antenna position on PCB is free-space electromagnetic radiation. The location and layout of the antenna are key factors to increase the data rate and transmission range.

Therefore, the layout of the module antenna location and routing is recommended as follows:

- 1. Place the antenna on the edge (corner) of the PCB.
- 2. Make sure that there is no signal line or copper foil in each layer below the antenna.
- 3. It is best to hollow out the antenna position in the following figure to ensure that the S11 of the module is minimally affected.

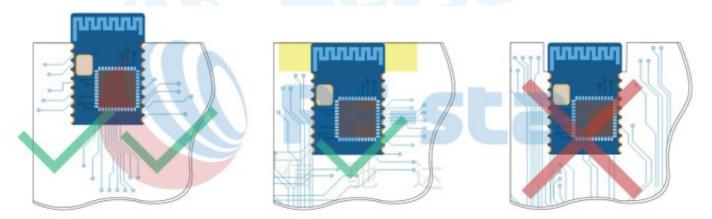


Figure 8. Recommendation of Antenna Layout

Note: The hollow-out position is based on the antenna used.



5.4.2 IPEX Connector Specification

RF-BM-S02I module is integrated the IPEX version 1 antenna seat, the specification of the antenna seat is as follows:

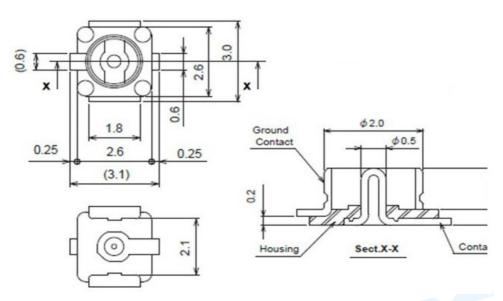


Figure 9. Specification of Antenna Seat

The specification of the IPEX wire end is as follows:

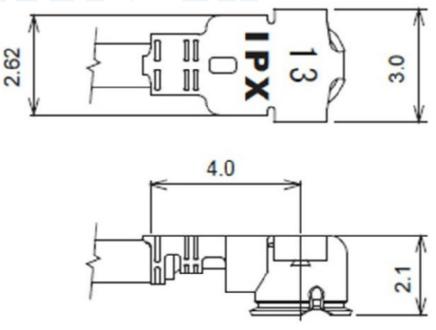


Figure 10. Specification of IPEX Wire

4.6 Basic Operation of Hardware Design

1. It is recommended to offer the module a DC stabilized power supply, a tiny power supply ripple coefficient, and reliable ground. Please pay attention to the correct connection between the positive and negative poles of the power



- supply. Otherwise, the reverse connection may cause permanent damage to the module;
- 2. Please ensure the supply voltage is between the recommended values. The module will be permanently damaged if the voltage exceeds the maximum value. Please ensure a stable power supply and no frequently fluctuating voltage.
- 3. When designing the power supply circuit for the module, it is recommended to reserve more than 30% of the margin, which is beneficial to the long-term stable operation of the whole machine. The module should be far away from the power electromagnetic, transformer, high-frequency wiring, and other parts with large electromagnetic interference.
- 4. The bottom of the module should avoid high-frequency digital routing, high-frequency analog routing, and power routing. If it has to route the wire on the bottom of the module, for example, it is assumed that the module is soldered to the Top Layer, the copper must be spread on the connection part of the top layer and the module, and be close to the digital part of the module and routed in the Bottom Layer (all copper is well-grounded).
- 5. Assuming that the module is soldered or placed in the Top Layer, it is also wrong to randomly route the Bottom Layer or other layers, which will affect the spurs and receiving sensitivity of the module to some degree;
- 6. Assuming that there are devices with large electromagnetic interference around the module, which will greatly affect the module performance. It is recommended to stay away from the module according to the strength of the interference. If circumstances permit, appropriate isolation and shielding can be done.
- 7. Assuming that there are routings of large electromagnetic interference around the module (high-frequency digital, high-frequency analog, power routings), which will also greatly affect the module performance. It is recommended to stay away from the module according to the strength of the interference. If circumstances permit, appropriate isolation and shielding can be done.
- It is recommended to stay away from the devices whose TTL protocol is the same 2.4 GHz physical layer, for example, USB 3.0.

4.7 Trouble Shooting

4.7.1 Unsatisfactory Transmission Distance

- When there is a linear communication obstacle, the communication distance will be correspondingly weakened.
 Temperature, humidity, and co-channel interference will lead to an increase in the communication packet loss rate.
 The performance of ground absorption and reflection of radio waves will be poor when the module is tested close to the ground.
- 2. Seawater has a strong ability to absorb radio waves, so the test results by the seaside are poor.
- 3. The signal attenuation will be very obvious if there is metal near the antenna or if the module is placed inside the metal shell.
- 4. The incorrect power register set or the high data rate in the open air may shorten the communication distance. The higher the data rate, the closer the distance.



- The low voltage of the power supply is lower than the recommended value at ambient temperature, and the lower the voltage, the smaller the power is.
- 6. The unmatchable antennas and modules or the poor quality of the antenna will affect the communication distance.

4.7.2 Vulnerable Module

- Please ensure the supply voltage is between the recommended values. The module will be permanently damaged
 if the voltage exceeds the maximum value. Please ensure a stable power supply and no frequently fluctuating
 voltage.
- 2. Please ensure the anti-static installation and the electrostatic sensitivity of high-frequency devices.
- 3. Due to some humidity-sensitive components, please ensure suitable humidity during installation and application. If there is no special demand, it is not recommended to use at too high or too low temperature.

4.7.3 High Bit Error Rate

- There are co-channel signal interferences nearby. It is recommended to be away from the interference sources or modify the frequency and channel to avoid interferences.
- 2. The unsatisfactory power supply may also cause garbled. It is necessary to ensure the power supply's reliability.
- 3. If the extension wire or feeder wire is of poor quality or too long, the bit error rate will be high.

4.8 Electrostatics Discharge Warnings

The module will be damaged by the discharge of static. RF-star suggests that all modules should follow the 3 precautions below:

- 1. According to the anti-static measures, bare hands are not allowed to touch modules.
- 2. Modules must be placed in anti-static areas.
- 3. Take the anti-static circuitry (when inputting HV or VHF) into consideration in product design. Static may result in the degradation in performance of the module, even causing failure.

4.9 Soldering and Reflow Condition

- 1. Heating method: Conventional Convection or IR/convection.
- 2. Solder paste composition: Sn96.5/Ag3.0/Cu0.5
- 3. Allowable reflow soldering times: 2 times based on the following reflow soldering profile.
- 4. Temperature profile: Reflow soldering shall be done according to the following temperature profile.
- Peak temperature: 245 ℃.



Table 6. Temperature Table of Soldering and Reflow

Profile Feature	Sn-Pb Assembly	Pb-Free Assembly
Solder Paste	Sn63 / Pb37	Sn96.5 / Ag3.0 / Cu0.5
Min. Preheating Temperature (T _{min})	100 ℃	150 ℃
Max. Preheating Temperature (T _{max})	150 ℃	200 ℃
Preheating Time (T _{min} to T _{max}) (t ₁)	60 s ~ 120 s	60 s ~ 120 s
Average Ascend Rate (T _{max} to T _p)	Max. 3 ℃/s	Max. 3 ℃/s
Liquid Temperature (T _L)	183 ℃	217 ℃
Time above Liquidus (t _L)	60 s ~ 90 s	30 s ~ 90 s
Peak Temperature (T _p)	220 ℃ ~235 ℃	230 ℃ ~ 250 ℃
Average Descend Rate (T _p to T _{max})	Max. 6 ℃/s	Max. 6 ℃/s
Time from 25 ℃ to Peak Temperature (t₂)	Max. 6 minutes	Max. 8 minutes
Time of Soldering Zone (t _P)	20±10 s	20±10 s

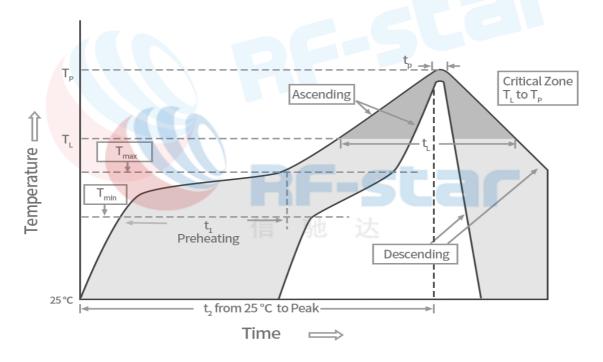


Figure 11. Recommended Reflow for Lead-Free Solder



5 Optional Package Specification

The default package method is **by tray**. If you need the modules to be shipped by tape & reel, pls contact us in advance.

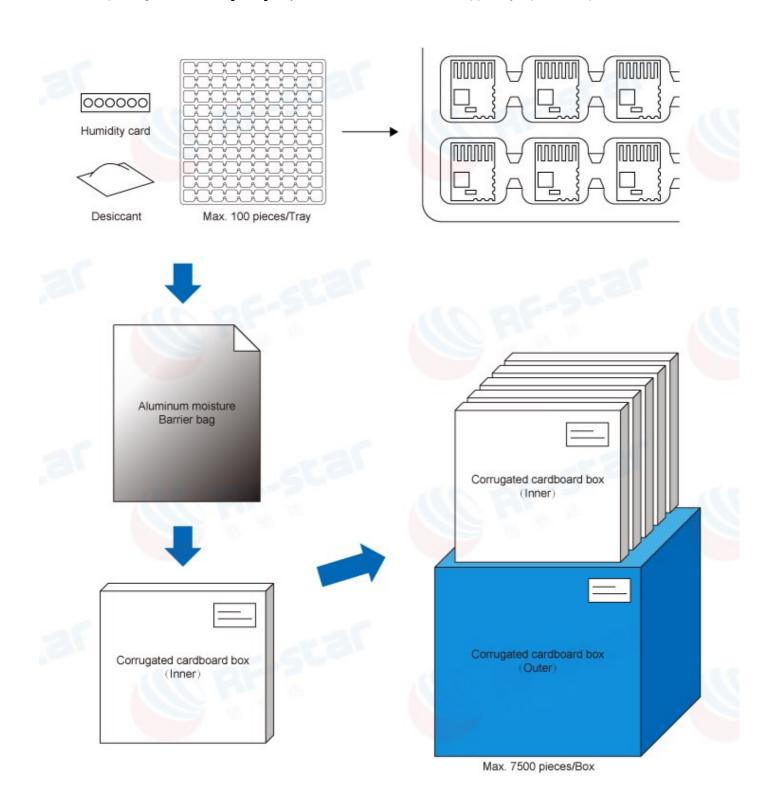


Figure 12. Default Package by Tray



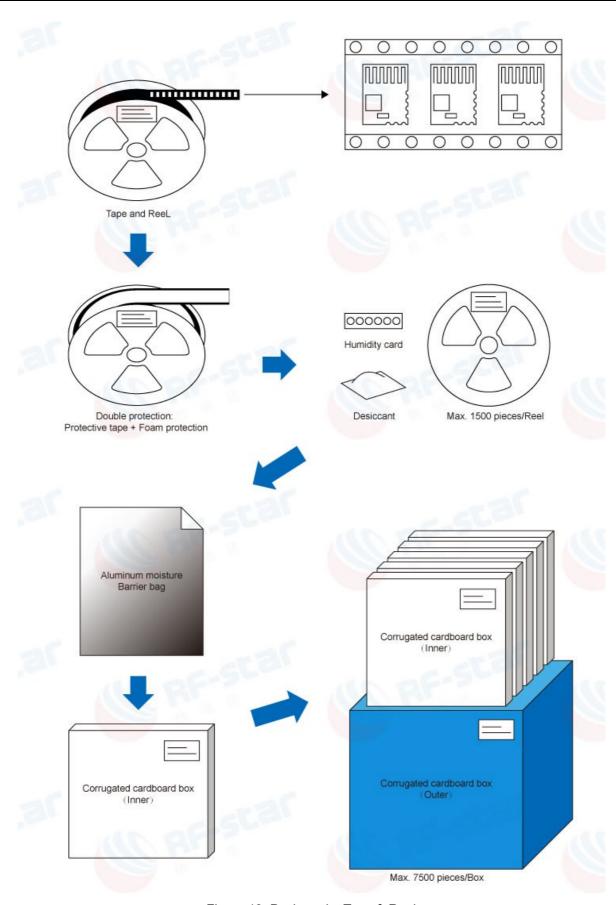


Figure 13. Package by Tape & Reel



6 Certification

6.1 FCC

This device complies with part 15 of the FCC Rules. Operation is subject to the following two conditions: (1) This device may not cause harmful interference, and (2) this device must accept any interference received, including interference that may cause undesired operation.

FCC ID: 2ABN2-RFBMS02



Figure 14. FCC Certificate

6.2 CE

Verification No.: CCISE170703301V



Figure 15. CE Certificate



6.3 RoHS

Report No.: DTI201801253515



Figure 16. RoHS Certificate

6.4 Reach

Reach Test Report No.: C150918025001



Figure 17. Reach Certificate



7 Revision History

Date	Version No.	Description
2018.01.23	V1.0	The initial version is released.
2018.02.07	V1.0	Update module picture.
2018.02.26	V1.0	Update module operating and storage temperature range. Add CE certificate.
2018.08.02	V1.0	Update company address.
2023.05.26	V1.0	Update MSL level. Update the Shenzhen office address.

Note:

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- 2. To obtain the latest document, please download it from the official website: www.szrfstar.com and www.szrfstar.com.



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